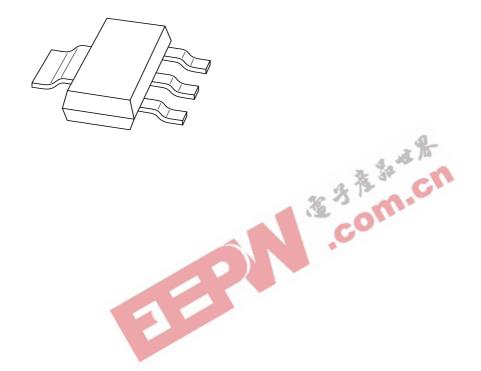
DISCRETE SEMICONDUCTORS

DATA SHEET



BAT120 seriesSchottky barrier double diodes

Product specification Supersedes data of 2001 Aug 27 2003 Aug 04





Schottky barrier double diodes

BAT120 series

FEATURES

- · Low switching losses
- Capability of absorbing very high surge current
- · Fast recovery time
- · Guard ring protected
- Plastic SMD package.

APPLICATIONS

- Low power switched-mode power supplies
- Rectification
- Polarity protection.

DESCRIPTION

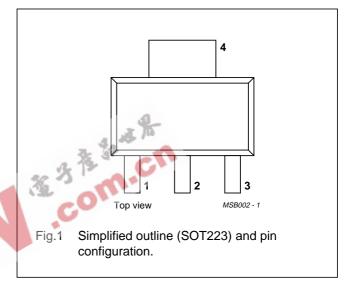
Planar Schottky barrier double diodes encapsulated in a SOT223 plastic SMD package.

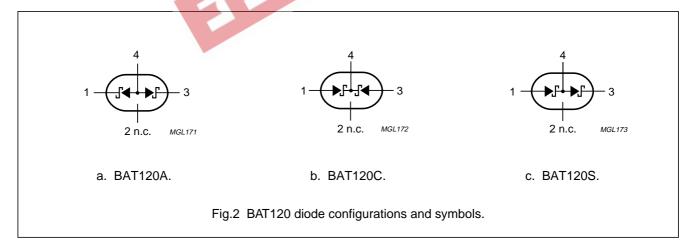
MARKING

TYPE NUMBER	MARKING CODE
BAT120A	AT120A
BAT120C	AT120C
BAT120S	AT120S

PINNING

PIN	BAT120						
PIN	Α	С	S				
1	k ₁	a ₁	a ₁				
2	n.c.	n.c.	n.c.				
3	k ₂	a_2	k ₂				
4	a ₁ , a ₂	k ₁ , k ₂	k ₁ , a ₂				





Schottky barrier double diodes

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT				
Per diode									
V _R	continuous reverse voltage		_	25	V				
I _F	continuous forward current		_	1	Α				
I _{FSM}	non-repetitive peak forward current	t _p < 10 ms; half sinewave; JEDEC method	_	10	А				
I _{RSM}	non-repetitive peak reverse current	t _p = 100 μs	_	0.5	Α				
T _{stg}	storage temperature		-65	+150	°C				
T _j	junction temperature		_	125	°C				
T _{amb}	operating ambient temperature		-65	+125	°C				

ELECTRICAL CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

		4 10-						
SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT			
Per diode		36 3						
V _F	forward voltage	see Fig.3						
		$I_{F} = 100 \text{ mA}$	260	300	mV			
		I _F = 1 A	400	450	mV			
I _R	reverse current	V_R = 20 V; note 1; see Fig.4	80	500	μΑ			
		V _R = 25 V; note 1; see Fig.4	_	1	mA			
		$V_R = 20 \text{ V}; T_j = 100 ^{\circ}\text{C}; \text{ note } 1$	_	10	mA			
C _d	diode capacitance	$f = 1 \text{ MHz}$; $V_R = 4 \text{ V}$; see Fig.5	100	_	pF			

Note

1. Pulse test: $t_p = 300 \ \mu s$; $\delta = 0.02$.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	note 1	100	K/W

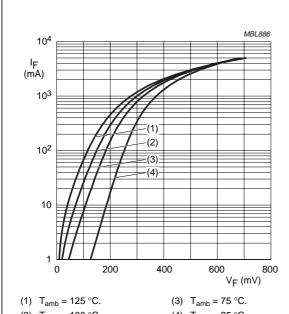
Note

1. Refer to SOT223 standard mounting conditions.

Schottky barrier double diodes

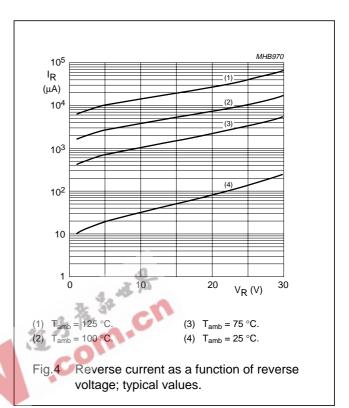
BAT120 series

GRAPHICAL DATA



- (2) $T_{amb} = 100 \, ^{\circ}C$.
- (4) $T_{amb} = 25 \,^{\circ}C$.

Fig.3 Forward current as a function of forward voltage; typical values.



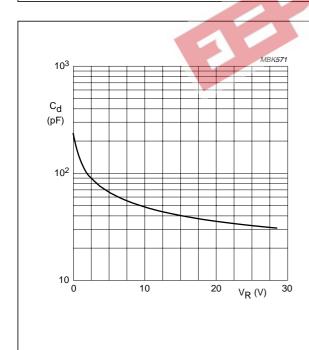


Fig.5 Diode capacitance as a function of reverse voltage; typical values.

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f = 1 MHz; $T_{amb} = 25 \,^{\circ}\text{C}$.

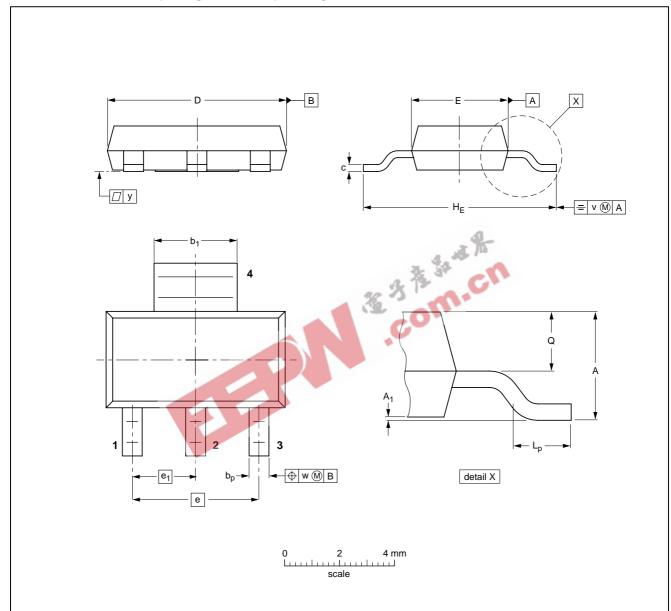
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PACKAGE OUTLINE

Plastic surface mounted package; collector pad for good heat transfer; 4 leads

SOT223



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UNIT	A	A ₁	bp	b ₁	С	D	E	е	e ₁	HE	Lp	Q	v	w	у
mm	1.8 1.5	0.10 0.01	0.80 0.60	3.1 2.9	0.32 0.22		3.7 3.3	4.6	2.3	7.3 6.7	1.1 0.7	0.95 0.85	0.2	0.1	0.1

OUTLINE		REFERENCES EUROPEAN ISSU				
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT223			SC-73			-97-02-28 99-09-13

Schottky barrier double diodes

BAT120 series

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS(2)(3)	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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